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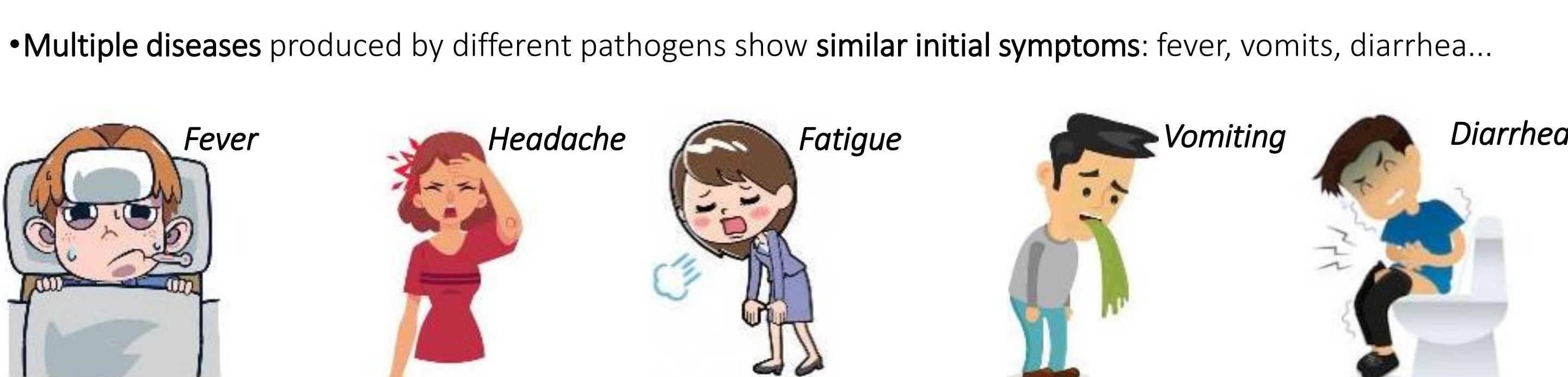


Silicon nanowire-based field-effect transistor array for multiple and rapid pathogen detection

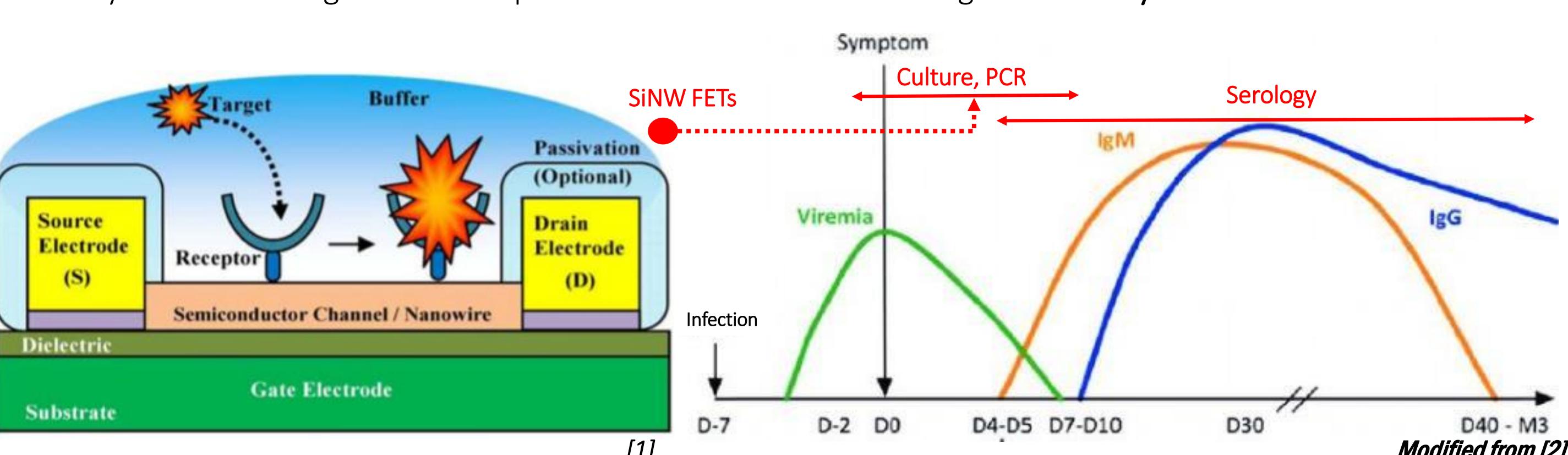
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Motivation



- Multiple diseases produced by different pathogens show similar initial symptoms: fever, vomits, diarrhea...
- In fast spreading pandemics, PCR diagnostics is slow and detection of immune reaction can be late.
- Early and direct detection of the antigen or the toxins would allow taking more immediate actions.
- Silicon nanowire-based field-effect transistors (SiNW FETs) are ultrasensitive devices compatible with microsystem technologies for mass production of devices containing sensor arrays

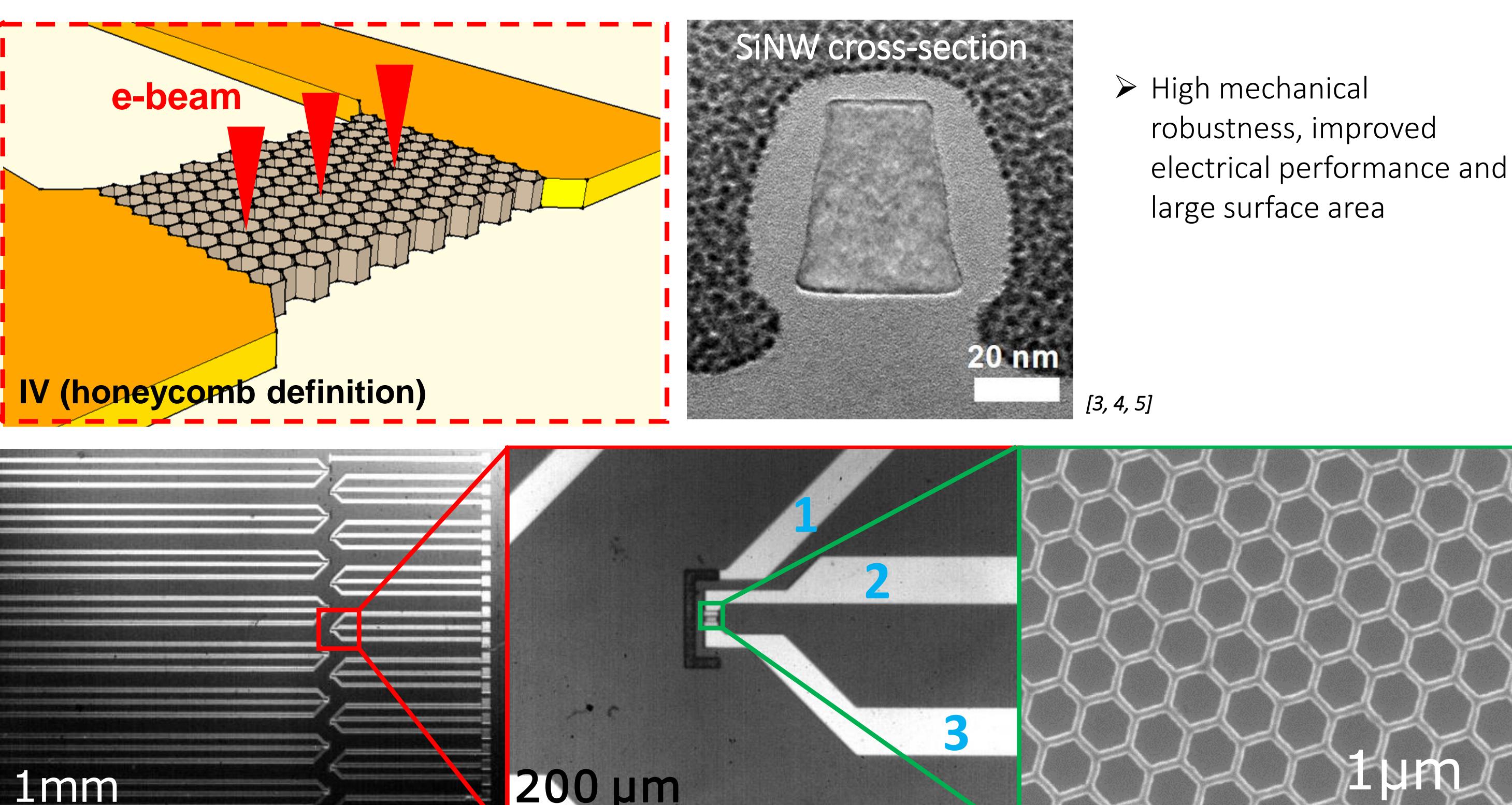


Objective: functionalization of SiNW FETs with antibodies for detection of and discrimination of the lethal Ebola disease from others causing similar initial symptoms.

Sensor fabrication and functionalization

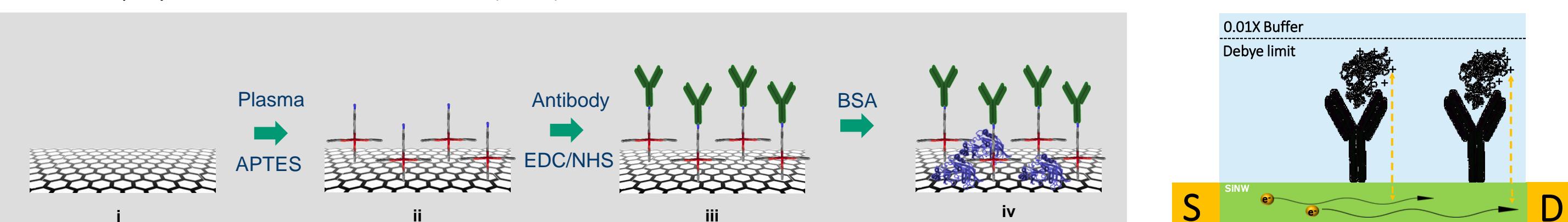
Design and fabrication

- Honeycomb structure patterning (HC-FET) by electron beam lithography
- 16 FETs aligned for microfluidic integration



Functionalization

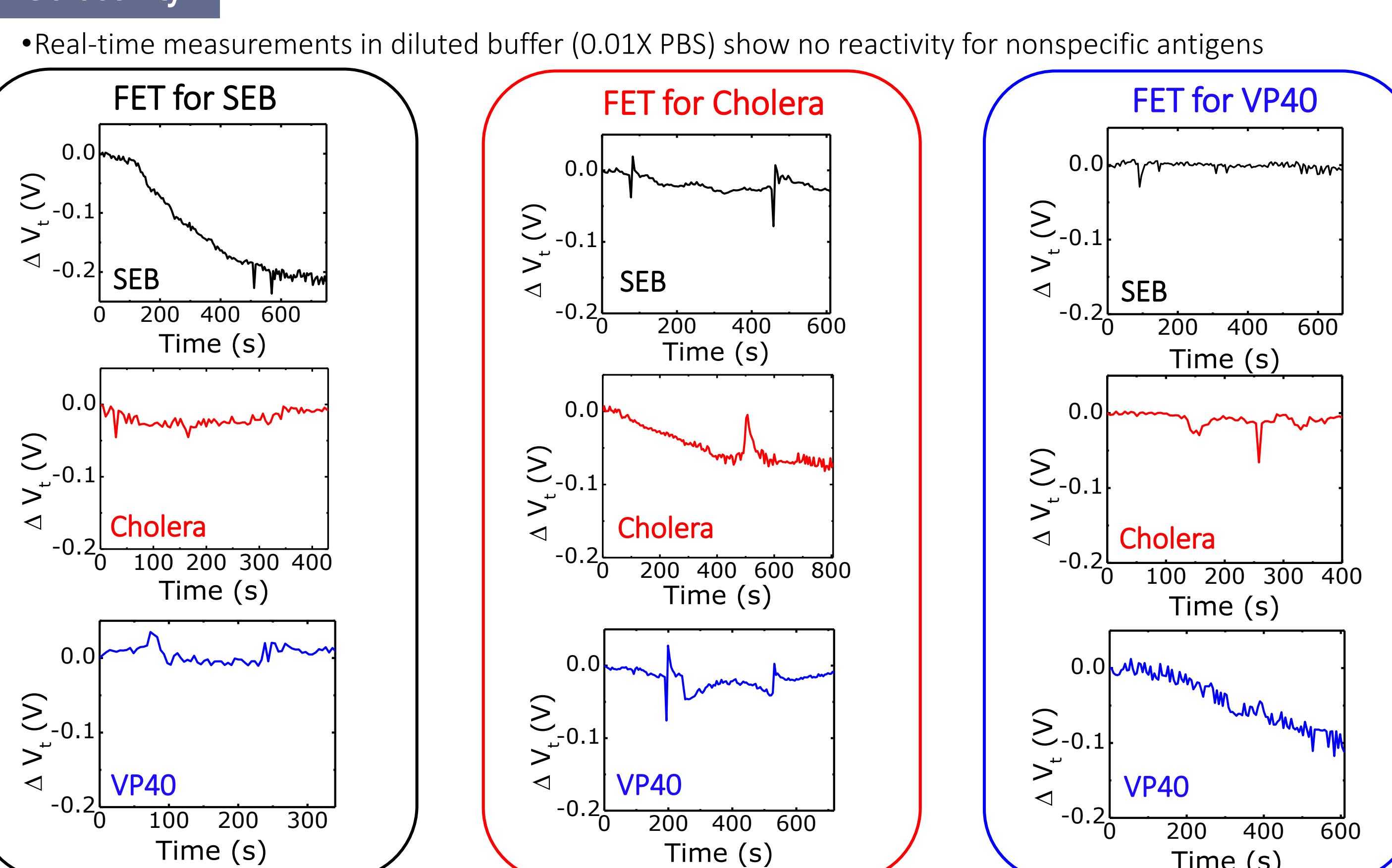
- Silane based covalent crosslinking of antibodies for:
 - VP40 matrix protein of Ebola virus (40% of the viral protein mass)
 - Cholera toxin subunit B
 - Staphylococcal enterotoxin B (SEB)



- Antigens attaching to antibodies will modulate FET conductance in diluted media

Biosensing

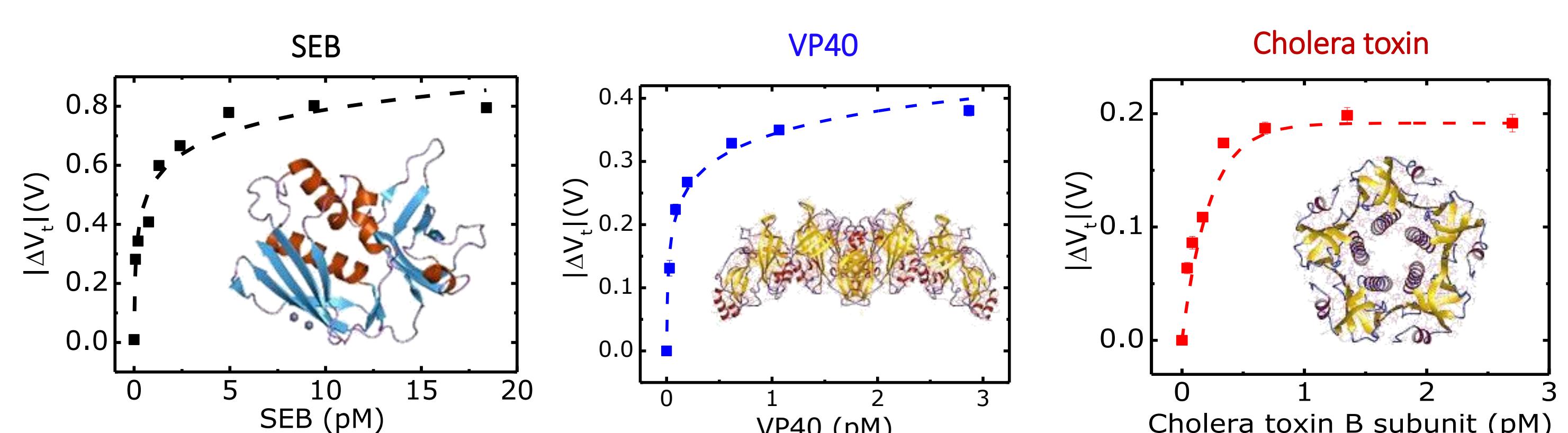
Selectivity



*500 fM antigen in all cases

Calibration

- Detection in femtomolar range and saturation in picomolar range



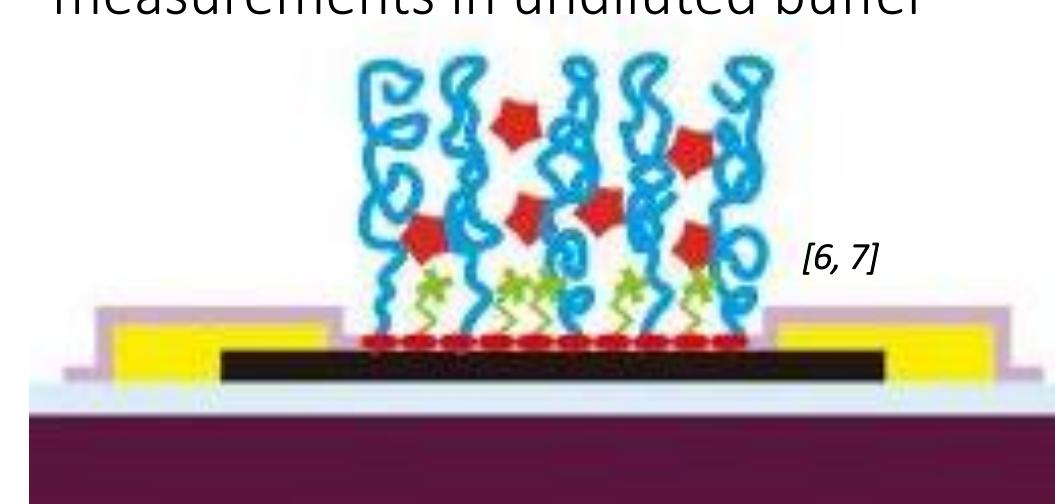
•Comparative table with state-of-the-art

Technique	Ebola detection	Miniaturization	Drawback
ELISA	nM	✗	Labeling
RT-PCR	10 ³ pfu/mL	✗	Error amplification, labeling, duration...
TEM	10 ⁶ VP/mL	✗	Special equipment
Plaque assay	10 ¹ pfu/mL	✗	Safety, duration
Flow cytometry	10 ⁵ pfu/mL	✗	Labeling
SPR	10 ⁶ pfu/mL	✓	-
SAW	10 ⁴ pfu/mL	✓	-
FET	fM	✓✓	-

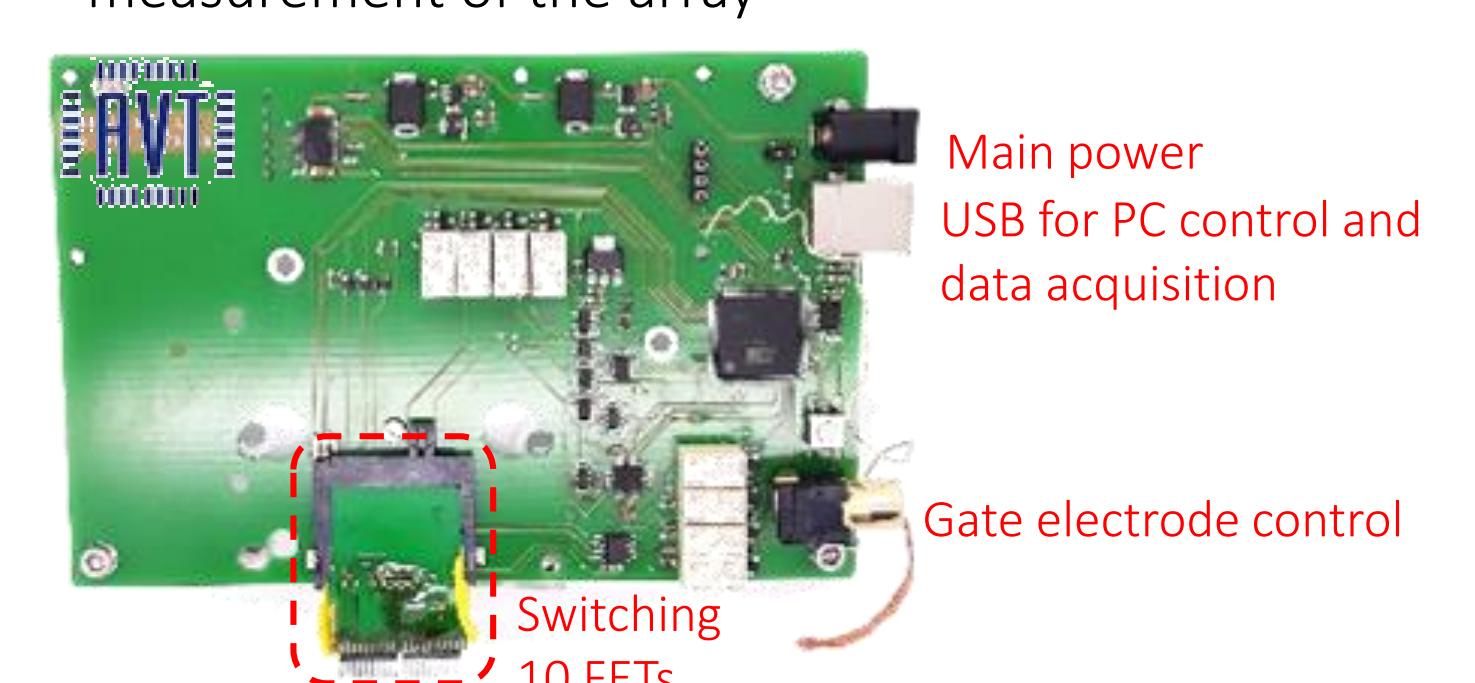
Conclusions and outlook

SiNW-FETs could enable rapid testing of pathogens in pandemic situation via direct antigen detection

- Dielectric polymers on surface will allow measurements in undiluted buffer



- Packaging with multiplexer will allow real time measurement of the array

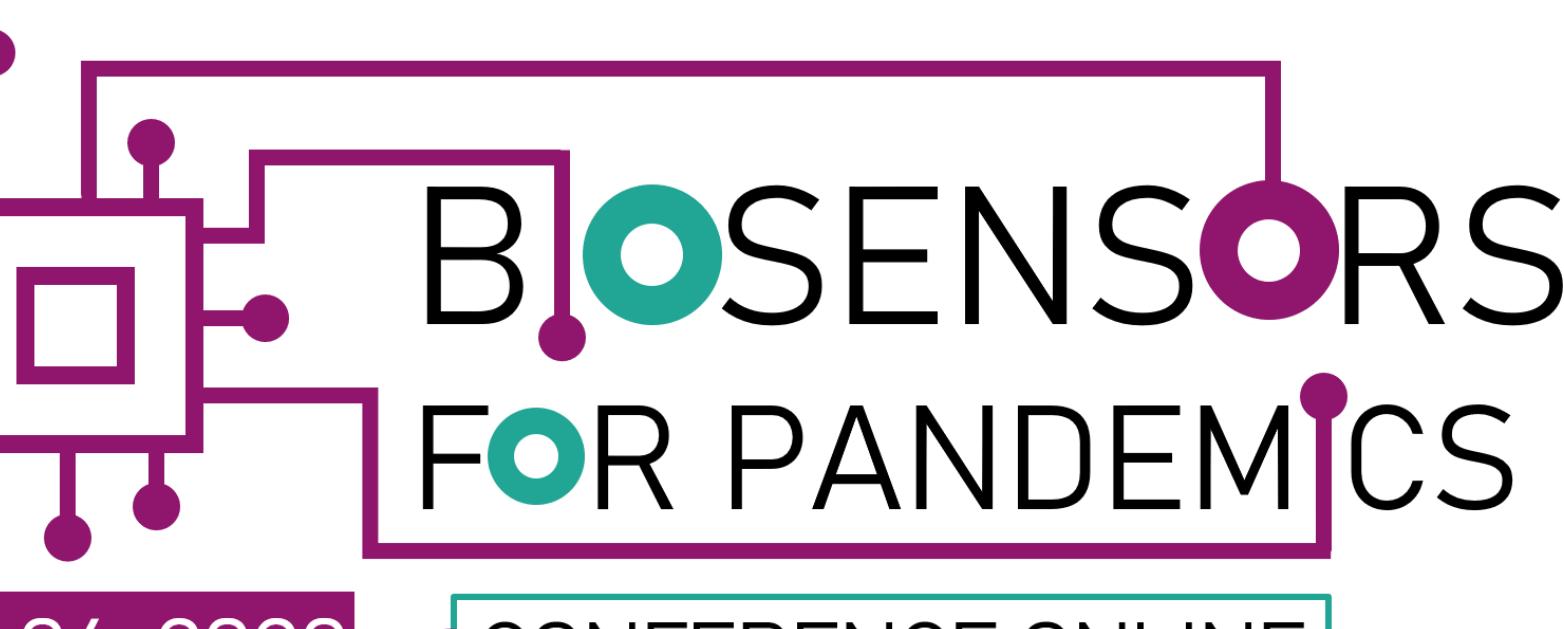


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